

# **MLA 150**

# THE ADVANCED MASKLESS ALIGNER









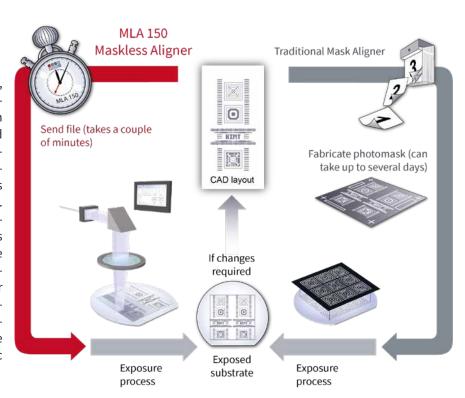
# **MLA 150**

## THE ADVANCED MASKLESS ALIGNER

The Maskless Aligner MLA 150 takes you into the future of photolithography: The traditional photomask becomes a thing of the past as your design file is exposed directly onto the resist-coated wafer via a 2-dimensional Spatial Light Modulator.

# THE NEW PHOTOLITHOGRAPHY CYCLE

In addition to flexibility and economy, MLA 150 provides non-contact exposure, outstanding ease of use, and high speed, making it the ideal tool in rapid prototyping environments, for lowto mid-volume production, and Research & Development. The Maskless Aligner was first introduced in 2015. Since then, the revolutionary, stateof-the-art maskless technology has become firmly established. Today, the MLA 150 serves as a trusted, indispensable workhorse in many multi-user facilities, nanofabrication labs, and national institutes. Application areas include MEMS, micro-optics, diffractive optical elements, sensors, electronic components, and many more.



# Data Laser Design SLM (Spatial Light Modulator) Focusing lens Scan width Writing strategy MLA 150

### THE RASTER SCAN WRITING STRATEGY

Directly modulated light illuminates the resist-covered surface according to the design data; this precise exposure immediately generates the pattern. This process is called "direct writing" – as opposed to projecting an image through a mask. The design layout is converted into a pixel image and during exposure, the image is created by projecting each pixel onto the photoresist through the optical system while the stage advances continuously. The Spatial Light Modulator effectively takes on the role of a programmable photomask.

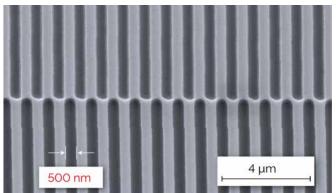
- High-speed Spatial Light Modulator (SLM)
- Bi-directional writing process
- "Empty stripes" optimization
- Ultra-fast x-y stage

### MLA 150 EXPOSURE TIMES \*

Laser wavelength	405 nm
50 x 50 mm <sup>2</sup>	4 minutes
100 x 100 mm <sup>2</sup>	9 minutes
150 x 150 mm <sup>2</sup>	16 minutes
200 x 200 mm <sup>2</sup>	36 minutes

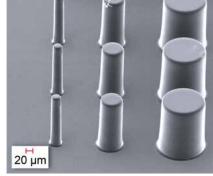
<sup>\*</sup>For exposure at 100 mJ/cm $^2$  and minimum feature size of 1  $\mu$ m

### **HIGH RESOLUTION**



High-resolution mode: Vertical 500 nm lines and spaces. Resist: S1805. Wavelength: 375 nm

### **HIGH-ASPECT-RATIO**



High-aspect ratio: Pillars. Resist: 160 μm SU-8

- Adjustable depth of focus
- Aspect ratio up to 1:20
- Applications: Micro-fluidics, MEMS, waveguides

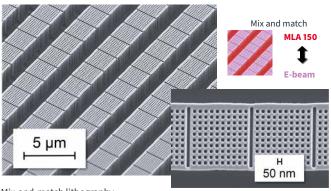
### FAST AND HIGH-PRECISION ALIGNMENT

- · Global and field-by-field alignment
- Backside alignment
- · Alignment accuracy of better than 500 nm
- Fast and easy alignment procedure
- Alignment error compensation: Corrects for rotation, offset, scaling and shearing
- Allows mix and match between different tool-sets, e.g. e-beam or thermal scanning probe lithography and laser lithography

SQUID magnetic flux sensor; 18 layer process

Courtesy of the Kirchhoff Institute for Physics, Heidelberg

### MIX-AND-MATCH APPLICATIONS

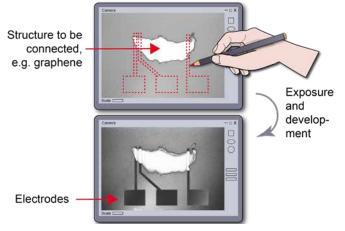


Mix-and-match lithography

Courtesy of EPFL LMIS1, Lausanne

### **FLEXIBILITY**

- The available solid-state laser sources (405 and 375 nm) make the system compatible with all broadband UV photoresists (including SU-8) and can both be installed in the MLA 150 at the same time
- 3D-patterning with grayscale lithography
- Optional: exchangeable chucks with individual vacuum layouts
- The Draw Mode: Add individual features to a previously patterned substrate. Using graphic elements, or even a bitmap, simply "draw" the desired structures such as labels, markers, or electrical connections directly into the camera image



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# SYSTEM SPECIFICATIONS

	Write Mode I *	Write Mode II *	
Writing performance			
Minimum feature size [μm]	0.6	1	
Minimum lines & spaces [μm]	0.8	1.2	
Global 2nd layer alignment [3σ, nm]	500	500	
Local 2nd layer alignment [3σ, nm]	250	250	
Backside alignment [3σ, nm]	1000	1000	
Exposure time 405 nm laser for 4" wafer [min]	35	9	
Exposure time 375 nm laser for 4" wafer [min]	35	20	
Max. write speed 405 nm laser [mm²/min]	285	1100	
Max. write speed 375 nm laser [mm²/min]	285	500	
System features			
Light source	Diode lasers: 8 W at 405 nm, 2.8 W a	Diode lasers: 8 W at 405 nm, 2.8 W at 375 nm, or both	
Substrate sizes	Variable: $3 \times 3 \text{ mm}^2$ to $6'' \times 6'' \mid \text{Optional}$ : $8'' \times 8''$		
	Customizable on request		
Substrate thickness	0 - 12 mm	0 - 12 mm	
Maximum exposure area	150 x 150 mm <sup>2</sup>   Optional: 200 x 200 r	150 x 150 mm <sup>2</sup>   Optional: 200 x 200 mm <sup>2</sup>	
Environmental chamber	Temperature stability ± 0.1°		
Real-time autofocus	Air-gauge or optical		
Autofocus compensation range	180 μm		
Grayscale	128 gray levels		
Software features	Exposure wizard, resist database, automatic labeling		
	and serialization, Draw Mode for CADless exposures,		
	substrate tracking / history		
Optional Automatic Loading System	<ul> <li>Can handle masks up to 7" and wafers up to 8"</li> </ul>		
	<ul> <li>A second cassette station, and a prealigner and wafer scanner are available as options</li> </ul>		
System dimensions (lithography unit)			
Height × width × depth	1950 mm × 1300 mm × 1300 mm	1950 mm × 1300 mm × 1300 mm	
Weight	1100 kg	1100 kg	
Installation requirements			
Electrical	230 VAC ± 5%, 50/60 Hz, 16 A	230 VAC ± 5%, 50/60 Hz, 16 A	
Compressed air	6 - 10 bar, stability ± 0.5 bar	6 - 10 bar, stability ± 0.5 bar	
Economical considerations			
Saves on the cost of photomasks			
Low running costs for maintenance, energy consumption	, spare parts		

Solid-state laser light sources with lifetime of several years

\* Only one write mode can be installed on the system Please note: Specifications depend on individual process conditions and may vary according to equipment configuration. Write speed depends on exposure area. Design and specifications are subject to change without prior notice.

Visit product website for more information

To contact your local representative, please consult our website heidelberg-instruments.com



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